

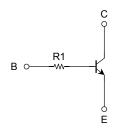
TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process) (Bias Resistor built-in Transistor)

RN1973

Switching, Inverter Circuit, Interface Circuit and Driver Circuit Applications.

- Two devices are incorporated into an Ultra-Super-Mini (6-pin) package
- Incorporating a bias resistor into a transistor reduces the parts count. Reducing the parts count enables the manufacture of ever more compact equipment and lowers assembly cost.
- Diverse resistance values are available suited to a range of different circuit designs.

Equivalent Circuit and Bias Resistor Values

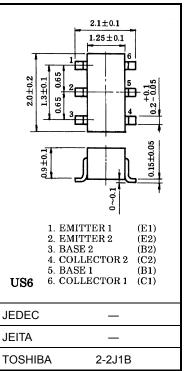


R1: 47 kΩ (Q1, Q2 common)

Maximum Ratings (Ta = 25°C) (Q1, Q2 common)

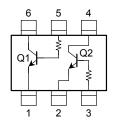
Characteristics	Symbol	Rating	Unit
Collector-base voltage	V _{CBO}	50	V
Collector-emitter voltage	V _{CEO}	50	V
Emitter-base voltage	V _{EBO}	5	V
Collector current	Ι _C	100	mA
Collector power dissipation	P _C (Note)	200	mW
Junction temperature	Tj	150	°C
Storage temperature range	T _{stg}	-55~150	°C

Note: Total rating



Weight: 0.0068 g (typ.)

Equivalent Circuit (top view)

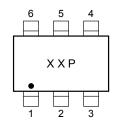


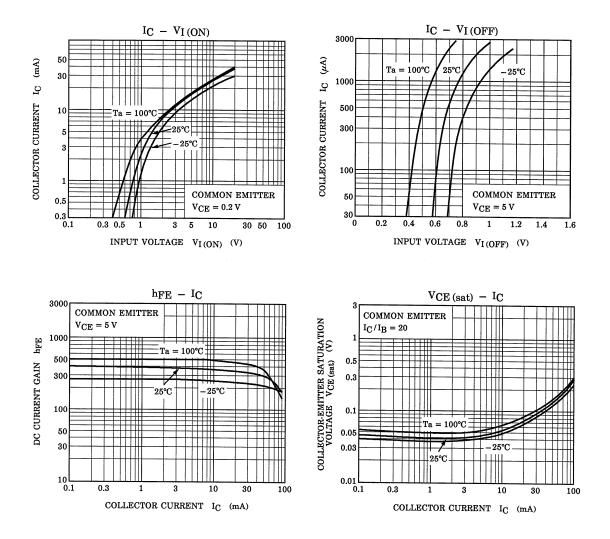
Unit: mm

Electrical Characteristics (Ta = 25°C) (Q1, Q2 common)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I _{CBO}	$V_{CB}=50~V,~I_{E}=0$	_	_	100	nA
Emitter cut-off current	I _{EBO}	$V_{EB}=5~V,~I_C=0$	_	_	100	nA
DC current gain	h _{FE}	$V_{CE} = 5 \text{ V}, I_C = 1 \text{ mA}$	120	_	700	
Collector-emitter saturation voltage	V _{CE (sat)}	$I_{C} = 5 \text{ mA}, I_{B} = 0.25 \text{ mA}$	_	0.1	0.3	V
Input resistor	R1	—	32.9	47	61.1	kΩ

Marking





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